SIEMENS

Data sheet 3RF2330-1AA25



Solid-state contactor 1-phase 3RF2 AC 51 / 30 A / 40 $^{\circ}\text{C}$ 48-600 V / 110-230 V AC screw terminal Blocking voltage 1200 V

and dust broad name	CIDILIC
product brand name	SIRIUS
product designation	solid-state contactor
design of the product	single-phase
product type designation	3RF23
manufacturer's article number	
_1 of the accessories that can be ordered	3RF2900-3PA88
• _4 of the accessories that can be ordered	3RF2950-0GA36
product designation	
_1 of the accessories that can be ordered	terminal cover
_4 of the accessories that can be ordered	load monitoring
General technical data	
product function	zero-point switching
power loss [W] for rated value of the current	
 at AC in hot operating state 	33 W
 at AC in hot operating state per pole 	33 W
 without load current share typical 	3.5 W
insulation voltage rated value	600 V
degree of pollution	3
type of voltage	
 of the operating voltage 	AC
 of the control supply voltage 	AC
surge voltage resistance of main circuit rated value	6 kV
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to DIN 40719 extended according to IEC 204-2 according to IEC 750	K
reference code according to EN 61346-2	Q
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	07/01/2006
SVHC substance name	Lead - 7439-92-1 Lead monoxide (lead oxide) - 1317-36-8 Dibutylbis(pentane-2,4-dionato-O,O')tin - 22673-19-4
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0
type of voltage of the operating voltage	AC
operating voltage	
• at AC	
— at 50 Hz rated value	48 600 V
— at 60 Hz rated value	48 600 V

operating frequency rated value	50 60 Hz
operating range relative to the operating voltage at AC	
• at 50 Hz	40 660 V
• at 60 Hz	40 660 V
operational current	
at AC-51 rated value	30 A
at AC-51 according to IEC 60947-4-3	22 A
according to UL 508 rated value	27 A
operational current minimum	500 mA
rate of voltage rise at the thyristor for main contacts	1 000 V/µs
maximum permissible	
blocking voltage at the thyristor for main contacts maximum permissible	1 200 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	600 A
I2t value maximum	1 800 A²·s
Control circuit/ Control	
type of voltage of the control supply voltage	AC
control supply voltage 1 at AC	
• at 50 Hz	110 230 V
• at 60 Hz	110 230 V
control supply voltage frequency	
1 rated value	50 Hz
• 2 rated value	60 Hz
control supply voltage at AC	
at 50 Hz full-scale value for signal<0> recognition	40 V
	40 V
at 60 Hz full-scale value for signal<0> recognition control supply voltage	70 V
control supply voltage	90 V
at AC initial value for signal <1> detection	
symmetrical line frequency tolerance	5 Hz
control current at minimum control supply voltage	0 0
• at AC	2 mA
control current at AC rated value	15 mA
ON-delay time	40 ms; additionally max. one half-wave
OFF-delay time	40 ms; additionally max. one half-wave
Auxiliary circuit	
type of switching contact	normally open contact (NO)
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method side-by-side mounting	Yes
fastening method	screw fixing and snap-on mounting on standard mounting rail 35 mm according to IEC 60715
design of the thread of the screw for securing the equipment	M4
height	95 mm
width	45 mm
depth	135.5 mm
Connections/ Terminals	
product component removable terminal for auxiliary and control circuit	Yes
type of electrical connection	
for main current circuit	screw-type terminals
for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	
• for main contacts	
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
finely stranded with core end processing	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²
for AWG cables for main contacts	2x (14 10)
connectable conductor cross-section for main contacts	
connectable conductor cross-section for main contacts	

 solid or stranded 	1.5 6 mm²
finely stranded with core end processing	1 10 mm²
type of connectable conductor cross-sections	
 for auxiliary and control contacts 	
— solid	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded with core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
— finely stranded without core end processing	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
for AWG cables for auxiliary and control contacts	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for main contacts	10 14
tightening torque	
for main contacts with screw-type terminals	2 2.5 N·m
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m
tightening torque [lbf·in]	
for main contacts with screw-type terminals	18 22 lbf-in
 for auxiliary and control contacts with screw-type terminals 	4.5 5.3 lbf·in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	7
• for main contacts	7 mm
for auxiliary and control contacts Electrical Safety	7 mm
Electrical Safety	IP20
protection class IP on the front according to IEC 60529 touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	ingor-sais, for vertical contact from the front
installation altitude at height above sea level maximum	1 000 m
ambient temperature	1 000 111
during operation	-25 +60 °C
during operation during storage	-55 +80 °C
Electromagnetic compatibility	
conducted interference	
due to burst according to IEC 61000-4-4	2 kV / 5 kHz behavior criterion 2
due to conductor-earth surge according to IEC 61000-4-5	2 kV behavior criterion 2
 due to conductor-conductor surge according to IEC 61000-4-5 	1 kV behavior criterion 2
ů ů	1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
61000-4-5due to high-frequency radiation according to IEC 61000-	
61000-4-5 ■ due to high-frequency radiation according to IEC 61000-4-6	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
61000-4-5 ■ due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
61000-4-5 ■ due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
61000-4-5 • due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
• due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments
• due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0
• due to high-frequency radiation according to IEC 61000- 4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335
• due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1
• due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032
• due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450
• due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable	140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1803-0 5SE1335 3NE8003-1 3NC1032 3NC1450
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manufacturer's article number

- of DIAZED fuse usable
- of NEOZED fuse usable

5SB311

relays

5SE2320: These fuses have a smaller rated current than the semiconductor relavs

Approvals Certificates

General Product Approval

EMV





Confirmation







Test Certificates

other

Railway

Environment

Type Test Certificates/Test Report

Special Test Certificate

Confirmation



Special Test Certificate Environmental Confirmations

Further informatior

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2330-1AA25

Cax online generator

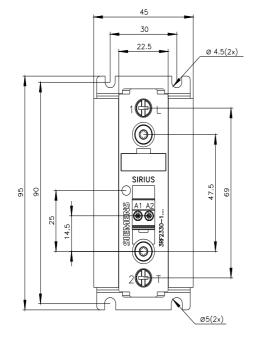
http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3RF2330-1AA25

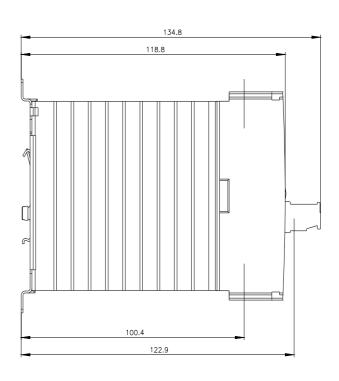
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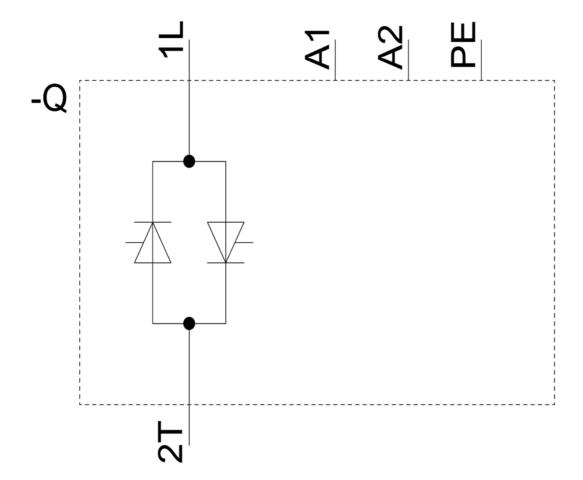
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Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

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